

## SNx4HCT574 Octal Edge-Triggered D-Type Flip-Flips With 3-State Outputs

### 1 Features

- Operating voltage range of 4.5V to 5.5V
- High-current 3-state noninverting outputs drive bus lines directly or up to 15 LSTTL loads
- Low power consumption, 80µA max I<sub>CC</sub>
- Typical  $t_{pd}$  = 22ns
- ±6mA output drive at 5V
- Low input current of 1µA max
- Inputs are TTL-voltage compatible
- **Bus-structured pinout**

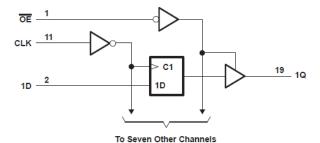
## 2 Description

These octal edge-triggered D-type flip-flops feature 3-state outputs designed specifically for bus driving. The 'HCT574 devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)	BODY SIZE(3)
	DGS (VSSOP, 20)	5.1mm × 4.9mm	5.1mm × 3mm
	DW (SOIC, 20)	12.80mm x 10.3mm	12.80mm x 7.50mm
SN74HCT574	DB (SSOP, 20)	7.2mm x 7.8mm	7.2mm x 5.30mm
SN/40C15/4	PDIP (20)	24.33mm × 9.4mm	24.33mm × 6.35mm
	NS (SOP, 20)	12.6mm x 7.8mm	12.6mm x 5.3mm
	PW (TSSOP, 20)	6.50mm x 6.4mm	6.50mm x 4.40mm

- For more information, see Section 11.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



Logic Diagram (Positive Logic)

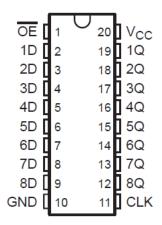


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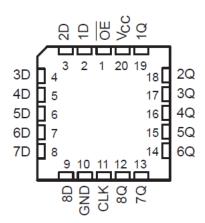
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## 3 Pin Configuration and Functions



DB, DGS, DW, N, NS, or PW package 20-Pin SSOP, SOIC, PDIP, SO, TSSOP Top View



FK Package 20-Pin LCCC Top View

Table 3-1. Pin Functions

NAME <sup>(1)</sup>	PIN	TYPE	DESCRIPTION
10E	1	I	Output enable 1
1A1	2	I	1A1 input
2Y4	3	0	2Y4 output
1A2	4	I	1A2 input
2Y3	5	0	2Y3 output
1A3	6	1	1A3 input
2Y2	7	0	2Y2 output
1A4	8	I	1A4 input
2Y1	9	0	2Y1 output
GND	10	_	Ground pin
2A1	11	I	2A1 input
1Y4	12	0	1Y4 output
2A2	13	1	2A2 input
1Y3	14	0	1Y3 output
2A3	15	I	2A3 input
1Y2	16	0	1Y2 output
2A4	17	I	2A4 input
1Y1	18	0	1Y1 output
20E	19	I	Output enable 2
VCC	20	_	Power pin

(1) I = input, O = output, P = power, FB = feedback, GND = ground, N/A = not applicable



## 4 Specifications

## 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	3 1 3 (	·	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_{l} < 0$ or $V_{l} > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±35	mA
	Continuous current through V <sub>CC</sub> or GNI	)		±70	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended" operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## **4.2 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)(1)

						SN74HCT574			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2			2			V
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V			0.8			0.8	V
VI	Input voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V
Vo	Output voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V
Δt/Δν	Input transition rise/fall time				500			500	ns
T <sub>A</sub>	Operating free-air temperate	ıre	-55		125	-40		85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

#### 4.3 Thermal Information

		DGS (VSSOP)	DW (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL METRIC		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance (1)	130.6	109.1	122.7	84.6	113.4	131.8	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	68.7	76	81.6	72.5	78.6	72.2	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	85.4	77.6	77.5	65.3	78.4	82.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	10.5	51.5	46.1	55.3	47.1	21.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	85.0	77.1	77.1	65.2	78.1	82.4	°C/W
R <sub>0</sub> JC(bot)	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	N/A	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

Product Folder Links: SN54HCT574 SN74HCT574

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



#### 4.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V <sub>cc</sub>	T	<sub>A</sub> = 25°C		SN54HC	T574	SN74HCT574		UNIT
PARAMETER				MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
V	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
V <sub>OH</sub>	VI = VIH OI VIL	I <sub>OH</sub> = −6 mA	4.5 V	3.98	4.3		3.7		3.84		·
V	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
V <sub>OL</sub>	VI - VIH OI VIL	I <sub>OL</sub> = 6 mA	4.5 V		0.17	0.26		0.4		0.33	·
I <sub>I</sub>	$V_I = V_{CC}$ or 0		5.5 V		±0.1	±100		±1000		±1000	nA
I <sub>OZ</sub>	$V_O = V_{CC}$ or 0		5.5 V		±0.01	±0.5		±10		±5	μA
I <sub>cc</sub>	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	5.5 V			8		160		80	μA
ΔI <sub>CC</sub> (1)	One input at 0.9 Other inputs at	,	5.5 V		1.4	2.4		3		2.9	mA
C <sub>i</sub>			4.5 V to 5.5 V		3	10		10		10	pF

<sup>(1)</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.

## 4.5 Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted)

		V	T <sub>A</sub> = 25	5°C	SN54HC	T574	SN74HC	Г574	UNIT	
		V <sub>CC</sub>	MIN	MAX	MIN	MAX	MIN	MAX	UNII	
f	Clock fraguency	4.5 V		30		20		24	MU>	
f <sub>clock</sub>	Clock frequency	5.5 V		33		22		27	MHz	
	Dulas duration CLV high ar law	4.5 V	16		24		20		ns	
t <sub>w</sub>	Pulse duration, CLK high or low	5.5 V	14		22		18			
+	Saturatima data bafara CLKA	4.5 V	20		30		25		20	
t <sub>su</sub>	Setup time, data before CLK↑	5.5 V	17		27		23		ns	
4	Hold time data after CLIA	4.5 V	5		5		5			
t <sub>h</sub>	Hold time, data after CLK↑	5.5 V	5		5		5		ns	

## 4.6 Switching Characteristics, $C_L = 50 pF$

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	V	T	= 25°C		SN54HC	T574	SN74HC	T574	UNIT
PARAWIETER	(INPUT)	(OUTPUT)	V <sub>CC</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
f			4.5 V	30	36		20		24		MHz
f <sub>max</sub>			5.5 V	33	40		22		27		IVITIZ
4	CLK	Any Q	4.5 V		30	36		54	-	45	no
чрd	t <sub>pd</sub> CLK	Ally Q	5.5 V		25	32		48		41	ns
4	ŌĒ	Any Q	4.5 V		26	30		45		38	no
t <sub>en</sub>	OE	Ally Q	5.5 V		23	27		41		34	ns
	ŌĒ	Amy 0	4.5 V		23	30		45		38	
$t_{dis}$	OE	Any Q	5.5 V		22	27		41		34	ns
4		Any Q	4.5 V		10	12		18	-	15	no
t <sub>t</sub>		Ally Q	5.5 V		9	11		16		14	ns



# 4.7 Switching Characteristics, $C_L = 150 pF$

over recommended operating free-air temperature range, C<sub>L</sub> = 150 pF (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	V	TA	T <sub>A</sub> = 25°C		SN54HC	T574	SN74HCT574		UNIT
	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
£			4.5 V	30	36		20		24		MHz
f <sub>max</sub>			5.5 V	33	40		22		27		MHZ
	CLK Anv Q	4.5 V		40	53		80		66	20	
t <sub>pd</sub>	CLK	Any Q	5.5 V		35	47		71		60	ns
4	ŌĒ	Δπι. Ο	4.5 V		34	47		71		59	
<sup>L</sup> en	OE	Any Q	5.5 V		29	39		94		78	ns
		Any 0	4.5 V		18	42		63		53	
τ <sub>t</sub>		Any Q	5.5 V		16	38		57		48	ns

## 4.8 Operating Characteristics

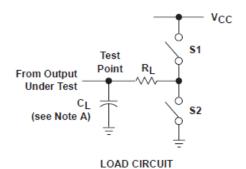
T<sub>A</sub> = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance per flip-flop	No load	93	pF

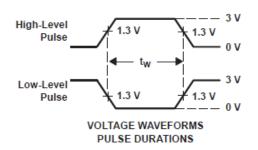
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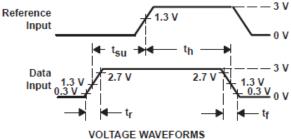
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### **5 Parameter Measurement Information**

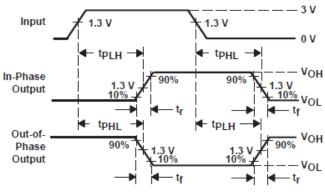


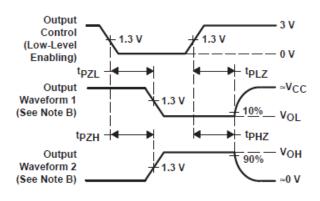
PARAI	PARAMETER		cL	<b>S1</b>	<b>S2</b>
	tpzH	1 kΩ	50 pF or	Open	Closed
ten	tpZL	1 K52	150 pF	Closed	Open
+ e-	tpHZ	1 kΩ	50 pF	Open	Closed
tdis	tpLZ	1 K22	30 pr	Closed	Open
t <sub>pd</sub> or	t <sub>pd</sub> or t <sub>t</sub>		50 pF or 150 pF	Open	Open





VOLTAGE WAVEFORMS
SETUP AND HOLD AND INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- A. C<sub>L</sub> includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_r$  = 6 ns,  $t_f$  = 6 ns.
- D. For clock inputs, fmaxis measured when the input duty cycle is 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- G.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- H.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 5-1. Load Circuit and Voltage Waveforms

## **6 Detailed Description**

#### 6.1 Overview

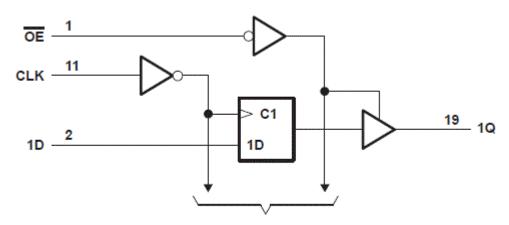
These octal edge-triggered D-type flip-flops feature 3-state outputs designed specifically for bus driving. The 'HCT574 devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight flip-flops enter data on the low-to-high transition of the clock (CLK) input.

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

#### 6.2 Functional Block Diagram



To Seven Other Channels

### 6.3 Device Functional Modes

Table 6-1. Function Table (Each Flip-Flop)

	OUTPUT		
ŌĒ	CLK	D	Q
L	<b>↑</b>	Н	Н
L	1	L	L
L	H or L	Х	Q <sub>0</sub>
Н	Х	Х	Z



## 7 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1µF and 1µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

#### 7.2 Layout

### 7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V<sub>CC</sub>, whichever makes more sense for the logic function or is more convenient.

## 8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 8.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.3 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 8.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

### 9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision G (July 2022) to Revision H (August 2024)	Page
•	Added DGS package to Device Information table, Pin Configuration and Functions section, and Therma	a/
	Information table	1
•	Added package size to Device Information table	1
•	Added Application and Implementation section	<mark>9</mark>
	, ,	

## 

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
SN74HCT574DBR	Active	Production	SSOP (DB)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT574
SN74HCT574DBR.A	Active	Production	SSOP (DB)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT574
SN74HCT574DGSR	Active	Production	VSSOP (DGS)   20	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT574
SN74HCT574DGSR.A	Active	Production	VSSOP (DGS)   20	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT574
SN74HCT574DW	Obsolete	Production	SOIC (DW)   20	-	-	Call TI	Call TI	-40 to 85	HCT574
SN74HCT574DWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574
SN74HCT574DWR.A	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HCT574
SN74HCT574DWRG4	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574
SN74HCT574N	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT574N
SN74HCT574N.A	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	SN74HCT574N
SN74HCT574NE4	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT574N
SN74HCT574NSR	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574
SN74HCT574NSR.A	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HCT574
SN74HCT574PW	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	-40 to 85	HT574
SN74HCT574PWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT574
SN74HCT574PWR.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT574
SN74HCT574PWT	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	-40 to 85	HT574

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.



## **PACKAGE OPTION ADDENDUM**

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(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT574DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74HCT574DGSR	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74HCT574DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HCT574DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HCT574NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HCT574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT574DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74HCT574DGSR	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74HCT574DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74HCT574DWR	SOIC	DW	20	2000	356.0	356.0	41.0
SN74HCT574NSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74HCT574PWR	TSSOP	PW	20	2000	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74HCT574N	N	PDIP	20	20	506	13.97	11230	4.32
SN74HCT574N.A	N	PDIP	20	20	506	13.97	11230	4.32
SN74HCT574NE4	N	PDIP	20	20	506	13.97	11230	4.32

## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. No JEDEC registration as of September 2020.
- 5. Features may differ or may not be present.





#### NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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